

NUP5120X6

5-Line Transient Voltage Suppressor Array

This 5-line voltage transient suppressor array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as cell phones, portables, computers, printers and other applications. This device features a monolithic common cathode design which protects five independent lines in a single SOT-563 package.

Features

- Protects up to 5 Lines in a Single SOT-563 Package
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model.
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8 kV (Contact)
- This is a Pb-Free Device

Applications

- Hand Held Portable Applications
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

MAXIMUM RATINGS (T_J = 25°C, unless otherwise specified)

Symbol	Rating	Value	Unit
P _{PK} 1	Peak Power Dissipation 8x20 μsec double exponential waveform, (Note 1)	90	W
T _J	Operating Junction Temperature Range	-40 to 125	°C
T _{STG}	Storage Temperature Range	-55 to 150	°C
T _L	Lead Solder Temperature – Maximum (10 seconds)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	16000 400 15000 8000	V

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Non-repetitive current pulse per Figure 1.

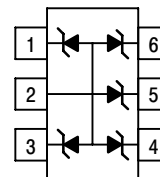


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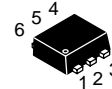
SOT-563 5-LINE TRANSIENT VOLTAGE SUPPRESSOR

PIN ASSIGNMENT

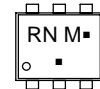


- PIN 1. CATHODE
- 2. ANODE
- 3. CATHODE
- 4. CATHODE
- 5. CATHODE
- 6. CATHODE

MARKING DIAGRAM



**SOT-563
CASE 463A
STYLE 6**



RN = Specific Device Code

M = Month Code

▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
NUP5120X6T1G	SOT-563 (Pb-Free)	4000/Tape & Reel
NUP5120X6T2G	SOT-563 (Pb-Free)	4000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, unless otherwise specified)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Reverse Working Voltage	(Note 2)	V_{RWM}		–	5.0	V
Breakdown Voltage	$I_T = 1 \text{ mA}$, (Note 3)	V_{BR}	6.2	6.8	7.2	V
Reverse Leakage Current	$V_{RWM} = 3 \text{ V}$	I_R	–	0.01	0.5	μA
Capacitance	$V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$ (Line to GND) $V_R = 2.5 \text{ V}$, $f = 1 \text{ MHz}$ (Line to GND)	C_J	–	54	70	pF

2. TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
3. V_{BR} is measured at pulse test current I_T .

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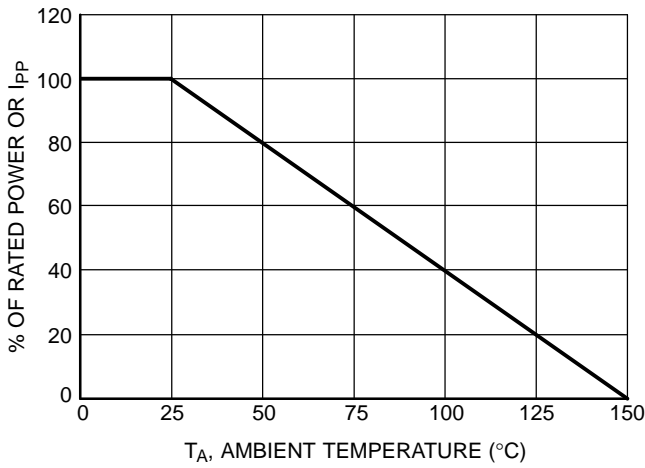


Figure 1. Power Derating vs. Ambient Temperature

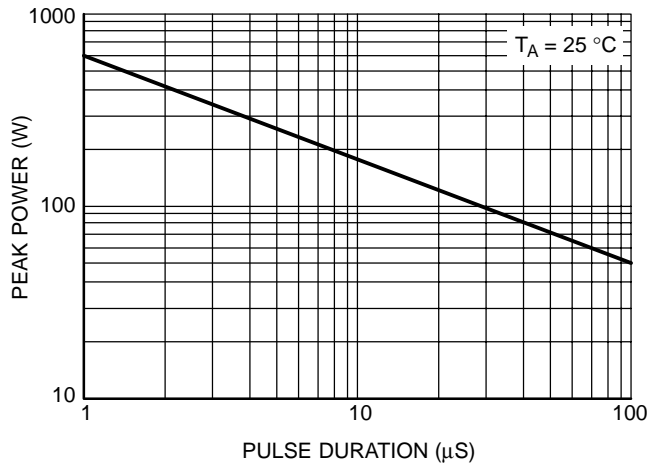


Figure 2. Peak Power vs. Pulse Duration

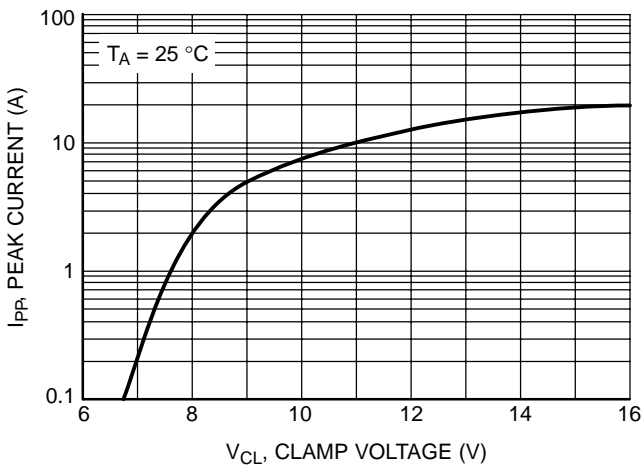


Figure 3. Peak Current vs. Clamp Voltage

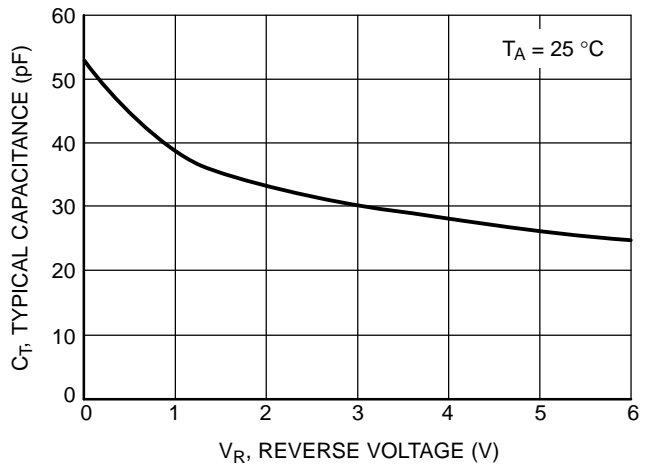


Figure 4. Typical Capacitance vs. Reverse Voltage

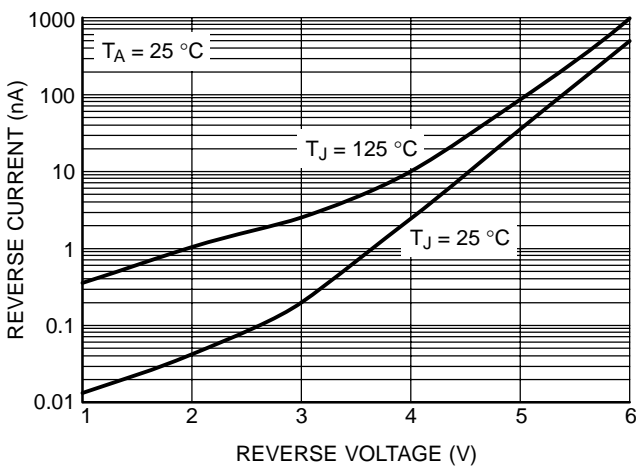


Figure 5. Reverse Current vs. Reverse Voltage

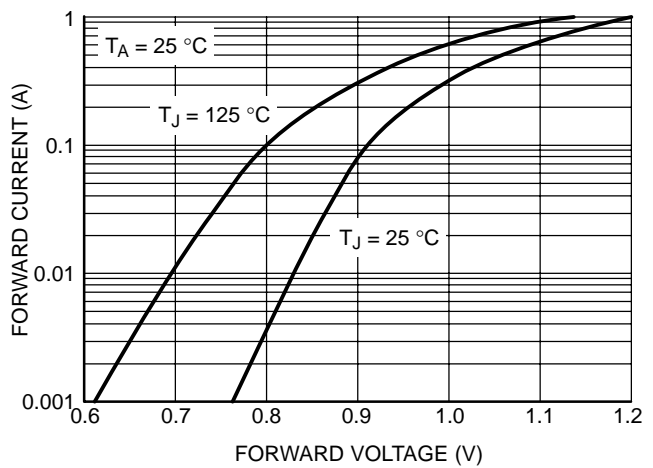
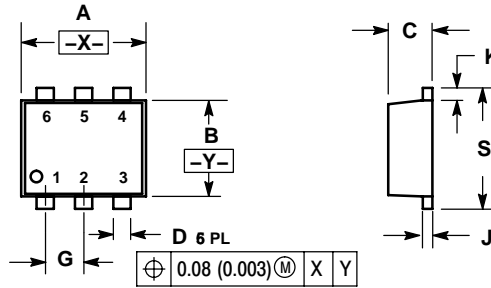


Figure 6. Typical Forward Current vs. Forward Voltage

NUP5120X6

PACKAGE DIMENSIONS

SOT-563, 6 LEAD
CASE 463A-01
ISSUE B



NOTES:

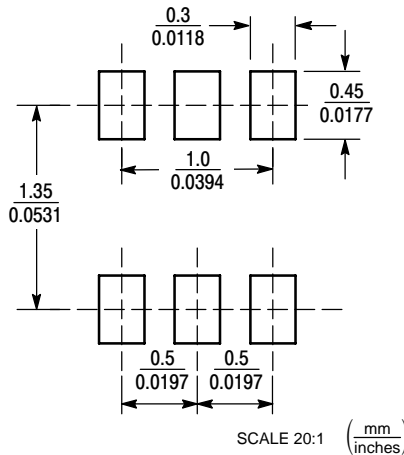
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.50	1.70	0.059	0.067
B	1.10	1.30	0.043	0.051
C	0.50	0.60	0.020	0.024
D	0.17	0.27	0.007	0.011
G	0.50 BSC		0.020 BSC	
J	0.08	0.18	0.003	0.007
K	0.10	0.30	0.004	0.012
S	1.50	1.70	0.059	0.067

STYLE 6:

- PIN 1. CATHODE
2. ANODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE

SOLDERING FOOTPRINT



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